









 	<h2 style="color: red;">FQU4N20TU</h2> <p>Hersteller-Teilenummer: FQU4N20TU</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 200V 3A IPAK</p> <p>Datenblätter:  FQU4N20TU.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 24190 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQU4N20TU
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 200V 3A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	24190 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	2.5W (Ta), 30W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	3A (Tc)
Rds On (Max) @ Id, Vgs	1.4 Ohm @ 1.5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6.5nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	220pF @ 25V
Verpackung	Tube



















































FQU4N20TU ist neu im Original, Suche FQU4N20TU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQU4N20TU Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQU4N20TU: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQU4N20 F FQU4N20 F</p>	 <p>FQU3P50TU AMI Semiconductor / ON Semiconductor MOSFET P-CH 500V 2.1A IPAK</p>	 <p>FQU4N25TU Fairchild/ON Semiconductor MOSFET N-CH 250V 3A IPAK</p>	 <p>FQU4N20TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 3A IPAK</p>
 <p>FQU4N50TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 2.6A IPAK</p>	 <p>FQU4N25TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 3A IPAK</p>	 <p>FQU3P50TU Fairchild/ON Semiconductor MOSFET P-CH 500V 2.1A IPAK</p>	 <p>FQU4N20LTU Fairchild/ON Semiconductor FQU4N20LTU FAIRCHILD</p>

heiße Teile

Mehr

 FQU2N50B	 FQU2N50BTU	 FQU2N50BTU	 FQU2N60/SSU2N60	 FQU2N60A
 FQU2N60B	 FQU2N60C	 FQU2N60CTU	 FQU2N60CTU	 FQU2N65C
 FQU2N90TU	 FQU2N90TU	 FQU30N06L	 FQU3N40TU	 FQU3N40TU
 FQU3N50C	 FQU3N50CTU	 FQU3N50CTU	 FQU3N60C	 FQU3N60CTU
 FQU3N60CTU	 FQU3N60TU	 FQU3N60TU	 FQU4N20LTU	 FQU4N20TU
 FQU4N25TU	 FQU4N25TU	 FQU4N50TU	 FQU4N50TU	 FQU4N50TU_WS
 FQU4N60C	 FQU4P25TU	 FQU4P25TU	 FQU5N40TU	 FQU5N40TU
 FQU5N50C	 FQU5N50CS	 FQU5N50CTU	 FQU5N50CTU	 FQU5N60C
 FQU5N60CTU	 FQU5N60CTU	 FQU5N65C	 FQU5P20TU	 FQU5P20TU
 FQU6N40C	 FQU6N60C	 FQU6N65C	 FQU7N10L	 FQU7N10TU

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